SCS308AH

SiC Schottky Barrier Diode

Datasheet

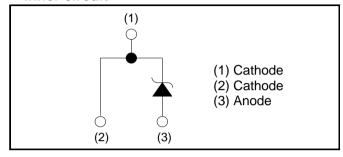
V_R	650V
I _F	8A
Q_C	21nC

Outline TO-220ACP (1) (2) (3)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

•Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS308AH

Construction

Silicon carbide epitaxial planar type

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
		•		
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	I current (T _c = 135°C)	I _F	8	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		67	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	57	А
	PW=10μs square, T _j =25°C		250	А
Repetitive peak forward current		I _{FRM}	36 ^{*1}	А
1≦PW≦10ms, T _j =25°C		۲۰2 بر	22	A ² s
i ² t value	1≦PW≦10ms, T _j =150°C	$\int i^2 dt$	16	A ² s
Total power disspation		P_{D}	57 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			I Imit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =40μA	650	-	-	V
	V _F	I _F =8A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =8A,T _j =150°C	-	1.44	1.71	V
		I _F =8A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.024	40	μΑ
		V _R =650V,T _j =150°C	-	1.6	160	μΑ
		V _R =650V,T _j =175°C	-	4.8	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	400	-	pF
		V _R =650V,f=1MHz	-	36	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	21	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	110	-	mJ

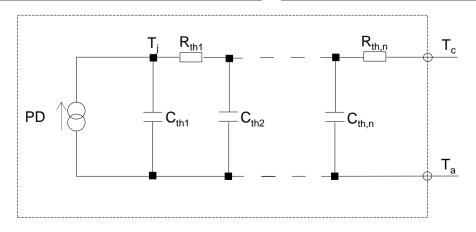
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.8	2.6	K/W

●Typical Transient Thermal Characteristics

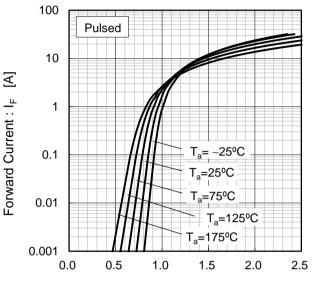
Symbol	Value	Unit
R _{th1}	1.89×10 ⁻²	
R _{th2}	1.81×10 ⁻¹	K/W
R _{th3}	1.55×10 ⁰	

Symbol	Value	Unit
C_{th1}	1.95×10 ⁻⁴	
C_{th2}	8.01×10 ⁻⁴	Ws/K
C_{th3}	1.82×10 ⁻³	



•Electrical characteristic curves

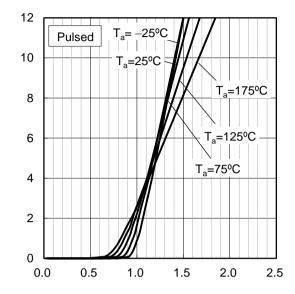
Fig.1 V_F - I_F Characteristics



Forward Voltage : V_F [V]

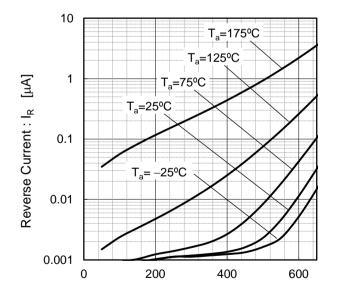
Fig.2 V_F - I_F Characteristics

Forward Current : IF [A]



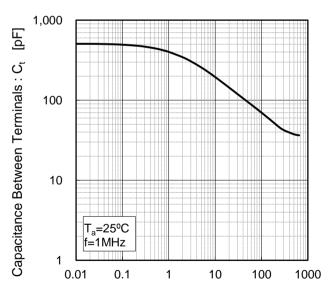
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

• Electrical characteristic curves

vs. Pulse Width

10

T_a=25°C
Single Pulse

1

0.01

0.000001

0.001

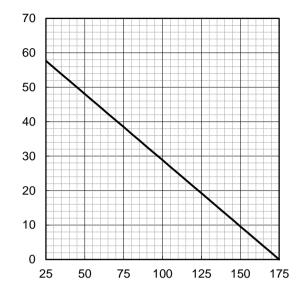
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Fig.5 Typical Transient Thermal Resistance

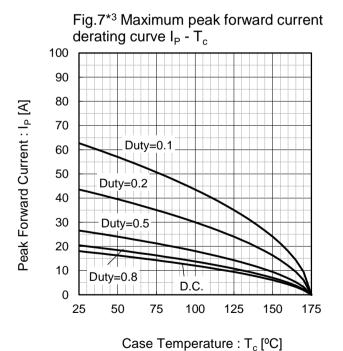
Pulse Width : P_w [s]

Fig.6 Power Dissipation

Power Dissipation [W]



Case Temperature : T_c [°C]



*3 Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

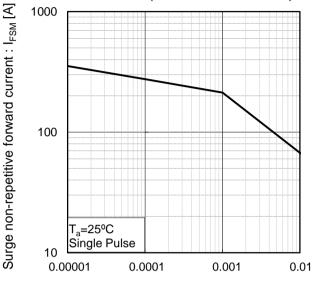
derating curve I_P - T_c (Not guaranteed) 100 90 Duty=0.1 80 Peak Forward Current: Ip [A] 70 Duty=0.2 60 50 Duty=0.5 40 30 20 Duty=0.8 10 D.C. 0 25 50 75 100 125 175 150

Fig.8*4 Typical peak forward current

Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

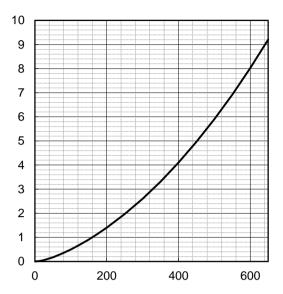
●Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: P_W [s]

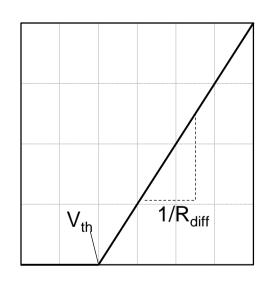
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.66×10 ⁻¹	V
a ₁	-1.1×10 ⁻³	V/°C
b ₀	4.40×10 ⁻²	Ω
b ₁	9.33×10 ⁻⁵	Ω/°C
b ₂	9.60×10 ⁻⁷	Ω/°C ²

 T_i in °C; -55 °C < T_i < 175°C; I_F < 16 A

Forward Current: IF

Capacitance stored energy : E_C[പ്വ]

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